

REMARKS

In response to the non-final Office Action, dated October 24, 2002, the applicants hereby makes the following response. Claims 1-3, 5 and 7-24 are currently pending with claims 1, 17 and 24 being independent. In this response, claims 17, 20, 21 and 24 are being amended and claims 19 and 22 are being canceled.

Allowable Subject Matter

Claim 22 stands objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all the limitations of the base claim and any intervening claims. Claim 22 has been cancelled with the limitation incorporated into base claim 17. Claims 1-3, 5 and 7-16 are allowed.

Rejection Under 35 U.S.C. 102(b)

Claims 17-20 stand rejected under 35 U.S.C. 102(b) as being allegedly anticipated by *Mental* (U.S. Patent No. 4,617,195). Claim 24 stands rejected under 35 U.S.C. 102(b) as being allegedly anticipated by *Nakayama et al.* (Japanese Patent No. 405343183). Claim 17 has been amended to incorporate the limitations of cancelled claim 22 as suggested by the Examiner. Applicants respectfully traverse the rejection and request withdrawal of same.

Rejection Under 35 U.S.C. § 103(a)

Claims 17 and 19-23 stand rejected under 35 U.S.C. § 103(a) as being purportedly unpatentable over *Nakayama et al.* in view of *Mental*. Claim 17 has been amended to further as suggested by the Examiner to incorporate the allowable subject matter of claim 22. Applicants respectfully traverse the rejection and request withdrawal of same.

Applicant respectfully submits that since claims 17 and 24 are patentable, all dependent claims therefrom are also patentable.

CONCLUSION

The Applicants respectfully request withdrawal of the rejection and believe that the claims as presented represent allowable subject matter. However, if the Examiner desires, the Applicants' attorney is ready for a telephone interview to expedite prosecution. As always, the Examiner is free to call the undersigned at 312-876-7518.

Respectfully submitted,

By its attorney,

Brian J. Gill

Brian J. Gill

Date: *3/22*, 2003

(Registration No. 46,727)

Brian J. Gill
 SONNENSCHN NATH & ROSENTHAL
 PO Box 061080
 Wacker Drive Station, Sears Tower
 Chicago, IL 60606-1080
 312-876-7518

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3/14/03
 Date

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re U.S. Patent Application of:)
Naoyuki Veda et al.)
)
Serial No.: 09 808,317) Examiner: T. Clove
)
Filed: March 14, 2001) Group Art Unit: 2879
)
For: LIGHT EMITTING DEVICE AND)
ITS USE)
)

VERSION WITH MARKINGS TO SHOW CHANGES MADE**In The Claims**

17. (Once Amended) A light-emitting device comprising an inorganic layer including an emission region and provided between an anode and a cathode wherein said anode has a visible light transmittance of 35 to 75% wherein said anode comprises a metal selected from the group consisting of Ni, Ru, Ir, Rh, Pt, Pd, Re, Ti, Zr, Nb, Mo, and W and said anode has a dopant selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.

20. (Once Amended) A light emitting device according to claim [19] 17, wherein said anode comprises a metal compound having said metal and a material selected from the group consisting of oxides, nitrides and oxide-nitrides.

21 (Once Amended) A light emitting device according to claim [19] 17, wherein said anode comprises a plurality of layers, a first set of the layers having a material selected from the group comprising of zinc, indium or tin, a second of the layers having said material.

24. (Once Amended) A light-emitting device comprising a layer including an emission region and provided between an anode and a cathode wherein said anode has a visible light transmittance of 35 to 75%, a metal selected from the group consisting of Ni, Ru, Ir, Rh, Pt, Pd,

Re. Ti, Zr, Nb, Mo, and W, and a first layer comprising a first compound selected from the group consisting of zinc, indium, and tin and a second layer comprising said metal, and wherein said second layer has a thickness that is greater than 20 nm and less than or equal to 80 nm, the anode further including dopant selected from the group consisting of H, Li, Na, K, Rb, Cs, Cu, Ag, and Au.

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